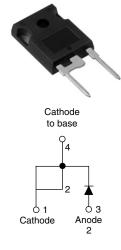
Vishay High Power Products

HEXFRED[®] Ultrafast Soft Recovery Diode, 25 A



TO-247AC modified

PRODUCT SUMMARY				
V _R	600 V			
V _F at 25 A at 25 °C	1.7 V			
I _{F(AV)}	25 A			
t _{rr} (typical)	23 ns			
T _J (maximum)	150 °C			
Q _{rr} (typical)	112 nC			
dl _{(rec)M} /dt (typical)	250 A/µs			
I _{RRM}	10 A			

FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Specified at operating conditions
- · Designed and qualified for industrial level

BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

HFA25PB60 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 25 A continuous current, the HFA25PB60 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{BBM}) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA25PB60 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _R		600	V	
Maximum continuous forward current	I _F	T _C = 100 °C	25		
Single pulse forward current	I _{FSM}		225	А	
Maximum repetitive forward current	I _{FRM}		100		
Movimum nouver discipation	P _D	T _C = 25 °C	151	W	
Maximum power dissipation		T _C = 100 °C	60	vv	
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C	

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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-	
	aximum forward voltage $V_{FM} = \frac{I_F = 25 \text{ A}}{I_F = 50 \text{ A}}$ See fig. 1 $I_F = 25 \text{ A}, T_J = 125 \text{ °C}$		-	1.3	1.7	v	
Maximum forward voltage		I _F = 50 A	See fig. 1	-	1.5	2.0	-
		I _F = 25 A, T _J = 125 °C		-	1.3	1.7	
Maximum reverse		$V_{R} = V_{R}$ rated	0	-	1.5	20	
leakage current	leakage current $T_{J} = 125 \text{ °C}, V_{R} = 0.8 \text{ x } V_{R} \text{ rated}$ See fig	See fig. 2	-	600	2000	μA	
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	55	100	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 12 -		-	nH		

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
D	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		23	-	
Reverse recovery time See fig. 5, 10	t _{rr1}	T _J = 25 °C		-	50	75	ns
See lig. 5, 10	t _{rr2}	T _J = 125 °C		-	105	160	
Peak recovery current	I _{RRM1}	T _J = 25 °C	I _F = 25 A dI _F /dt = 200 A/μs V _R = 200 V	-	4.5	10	A
See fig. 6, 10	I _{RRM2}	T _J = 125 °C		-	8.0	15	
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	112	375	nC
See fig. 7, 10	Q _{rr2}	T _J = 125 °C		-	420	1200	nc
Peak rate of fall of recovery current during t _h	dl _{(rec)M} /dt1	T _J = 25 °C		-	250	-	A/µs
See fig. 8, 10	dl _{(rec)M} /dt2	T _J = 125 °C		-	160	-	-7,μ5

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R _{thJC}		-	-	0.83	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	K/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.25	-	
Weight			-	6.0	-	g
Weight		-	0.21	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC modified (JEDEC)	HFA25PB60			



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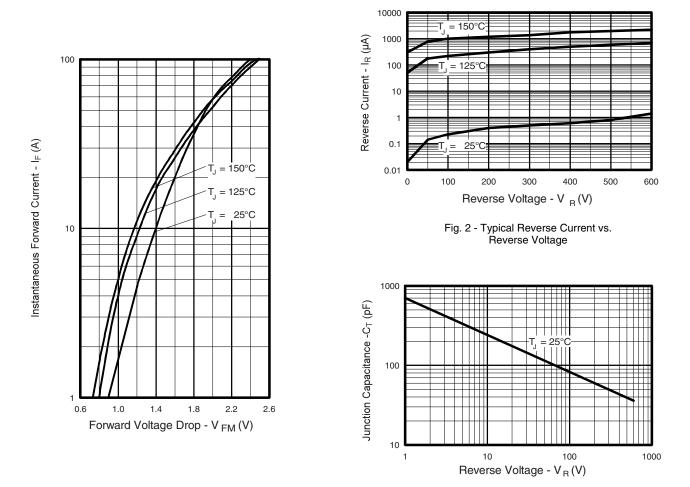


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

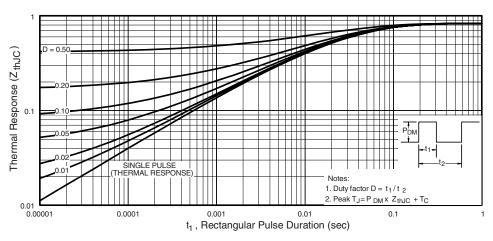


Fig. 4 - Maximum Thermal Impedance $Z_{thJC}\ Characteristics$

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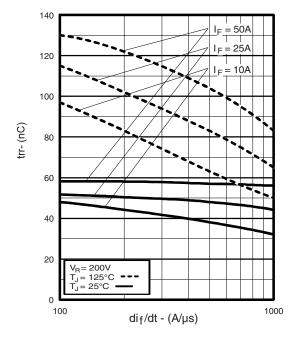
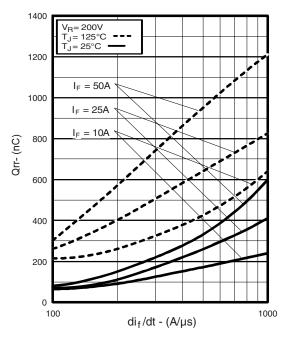


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt



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Fig. 7 - Typical Stored Charge vs. $dI_{\rm F}/dt$

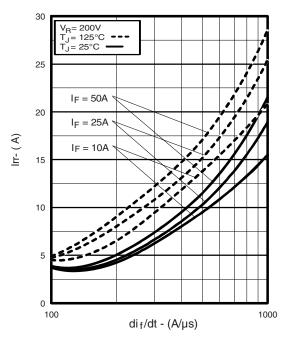


Fig. 6 - Typical Recovery Current vs. dl_F/dt

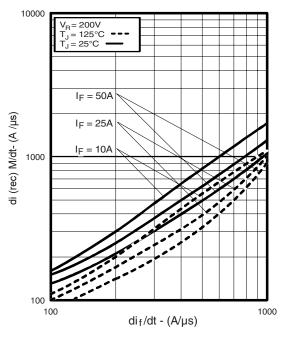


Fig. 8 - Typical $dI_{(rec)M}/dt vs. dI_F/dt$



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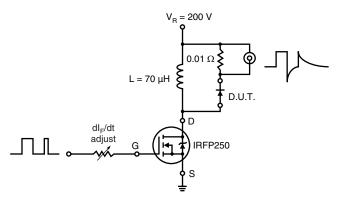


Fig. 9 - Reverse Recovery Parameter Test Circuit

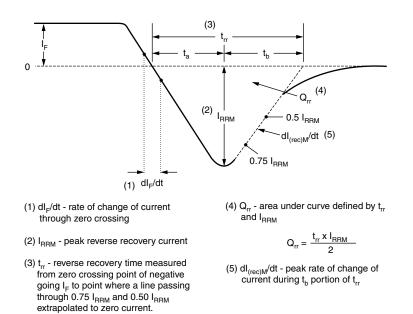


Fig. 10 - Reverse Recovery Waveform and Definitions

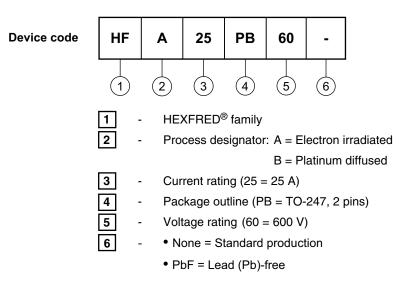
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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95253				
Part marking information	http://www.vishay.com/doc?95255			



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